NSN 5962-01-451-1414

Digital Microcircuit - Page 1 of 1



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Maximum Power Dissipation Rating:
500.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
3-state output and monolithic
Inclosure Configuration:
Leadless flat pack
Output Logic Form:
Bipolar metal-oxide semiconductor
Design Function And Quantity:
2 buffer and 2 driver, line
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, advanced bipolar cmos, octal buffer/driver with inverting three-state outputs, ttl compatible inputs, monolithic silicon
Voltage Rating And Type Per Characteristic:
-0.5 volts input and 7.0 volts input
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Quantity:
20 leadless
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
No
Fiig:
A458a0